

Surface Mount Schottky Barrier Rectifier

Reverse Voltage - 20 to 200V

Forward Current - 2.0A

FEATURES

- Metal silicon junction, majority carrier conduction
- For surface mounted applications
- Low power loss, high efficiency
- High forward surge current capability
- For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications

MECHANICAL DATA

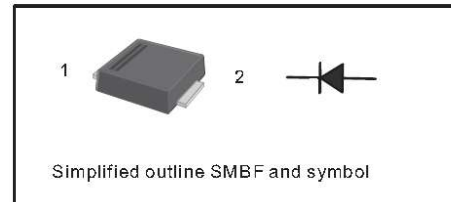
- Case: SMBF
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 57mg / 0.002oz

Absolute Maximum Ratings and Electrical characteristics

Ratings at 25°C ambient temperature unless otherwise specified. Single phase, half wave, 60Hz resistive or inductive load, for capacitive load, derate by 20 %

PINNING

PIN	DESCRIPTION
1	Cathode
2	Anode



Parameter	Symbols	SS22BF	SS24BF	SS28BF	SS28BF	SS210BF	SS212BF	SS215BF	SS220BF	Units
Maximum Repetitive Peak Reverse Voltage	V_{RRM}	20	40	60	80	100	120	150	200	V
Maximum RMS voltage	V_{RMS}	14	28	42	56	70	84	105	140	V
Maximum DC Blocking Voltage	V_{DC}	20	40	60	80	100	120	150	200	V
Maximum Average Forward Rectified Current	$I_{F(AV)}$	2.0								A
Peak Forward Surge Current, 8.3ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)	I_{FSM}	55				45				A
Max Instantaneous Forward Voltage at 2 A	V_F	0.55		0.70		0.85		0.95		V
Maximum DC Reverse Current $T_a = 25^\circ\text{C}$ at Rated DC Reverse Voltage $T_a = 100^\circ\text{C}$	I_R	0.5 5			0.3 3				mA	
Typical Junction Capacitance ¹⁾	C_j	250			110				pF	
Typical Thermal Resistance ²⁾	$R_{\theta JA}$	65								$^\circ\text{C/W}$
Operating Junction Temperature Range	T_j	-55 ~ +125								$^\circ\text{C}$
Storage Temperature Range	T_{sig}	-55 ~ +150								$^\circ\text{C}$

1) Measured at 1MHz and applied reverse voltage of 4 V D.C. 2) P.C.B. mounted with 0.5 X 0.5" (12.7 X 12.7 mm) copper pad areas.

SHIKE MAKE CONSCIOUS PRODUCT

CONSCIOUS PRODUCTS BEGIN WITH CONSCIOUS PEOPLE

REV.07



www.shike.tw

Fig.1 Forward Current Derating Curve

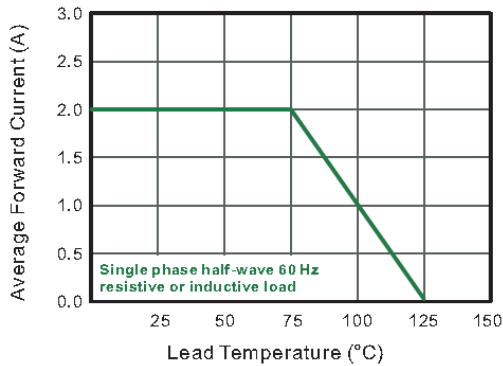


Fig.2 Typical Reverse Characteristics

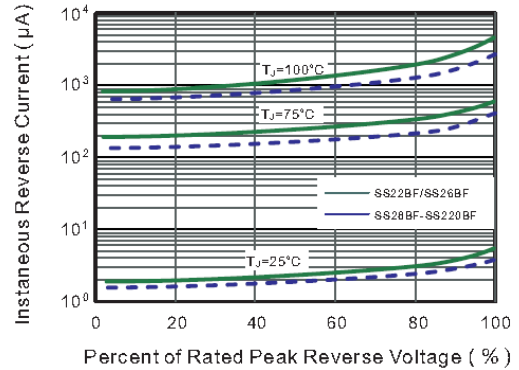


Fig.3 Typical Forward Characteristic

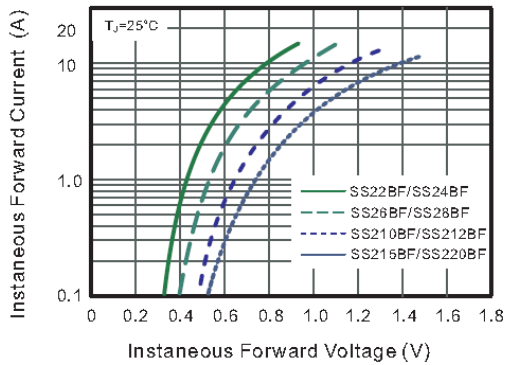


Fig.4 Typical Junction Capacitance

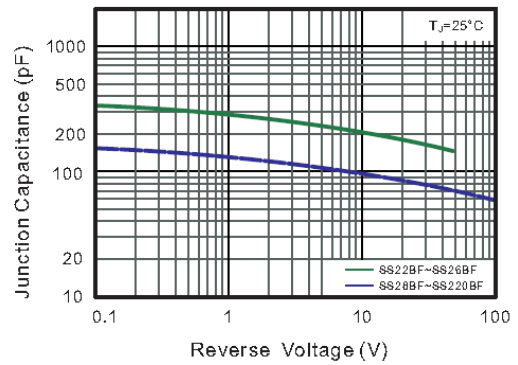


Fig.5 Maximum Non-Repetitive Peak Forward Surge Current

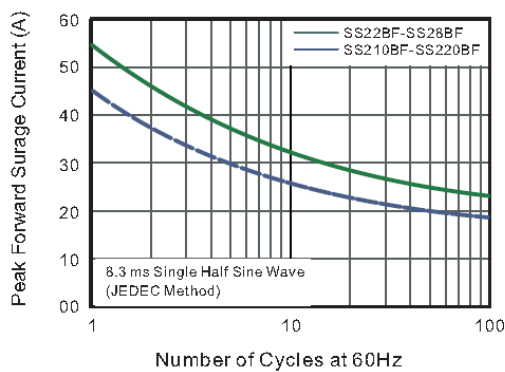
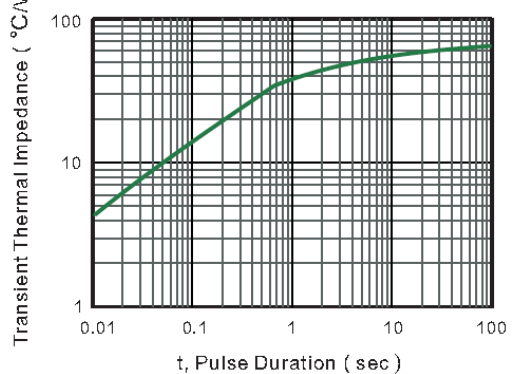


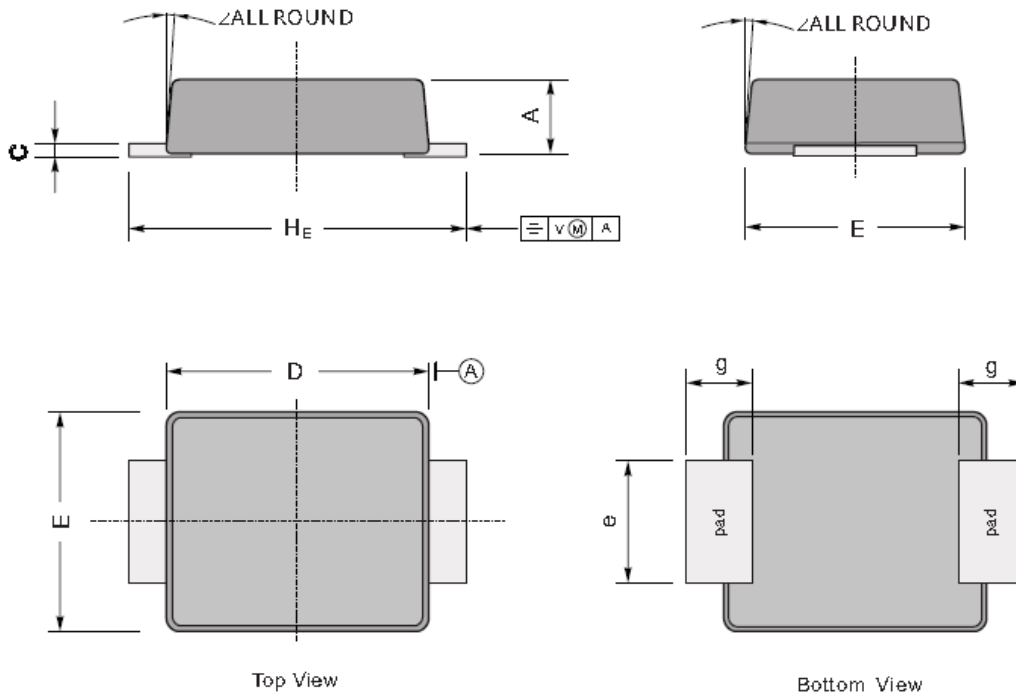
Fig.6- Typical Transient Thermal Impedance



PACKAGE OUTLINE

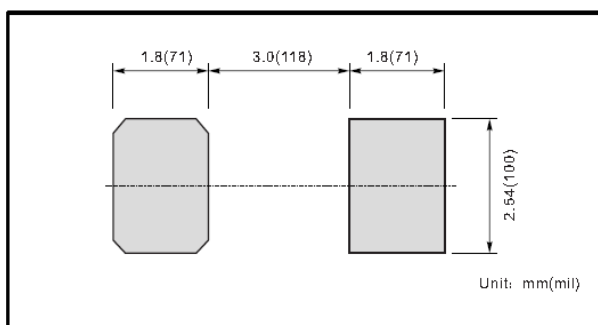
Plastic surface mounted package; 2 leads

SMBF



UNIT		A	C	D	E	H_E	e	g	\angle
mm	max	1.3	0.26	4.4	3.7	5.5	2.2	1.0	9°
	min	1.1	0.18	4.2	3.5	5.1	1.9		
mil	max	51	10	173	146	216	86	40	
	min	43	7	165	138	200	75		

The recommended mounting pad size



Marking

Type number	Marking code
SS22BF	S22B
SS24BF	S24B
SS26BF	S26B
SS28BF	S28B
SS210BF	S210B
SS212BF	S212B
SS215BF	S215B
SS220BF	S220B

SHIKE MAKE CONSCIOUS PRODUCT
CONSCIOUS PRODUCTS BEGIN WITH CONSCIOUS PEOPLE

REV.07



X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for [Schottky Diodes & Rectifiers](#) category:

Click to view products by [Shikues](#) manufacturer:

Other Similar products are found below :

[MA4E2039](#) [MA4E2508M-1112](#) [MBR10100CT-BP](#) [MBR1545CT](#) [MMBD301M3T5G](#) [GS1JE-TP](#) [RB160M-50TR](#) [BAS 3010S-02LRH E6327](#)
[BAT 54-02LRH E6327](#) [NSR05F40QNXT5G](#) [NSVR05F40NXT5G](#) [NTE555](#) [JANS1N6640](#) [SB07-03C-TB-H](#) [SB1003M3-TL-W](#)
[SBAT54CWT1G](#) [SBM30-03-TR-E](#) [SK310-T](#) [SK33A-TP](#) [SK34B-TP](#) [SS3003CH-TL-E](#) [PDS3100Q-7](#) [GA01SHT18](#) [CRS10I30A\(TE85L,QM](#)
[MA4E2501L-1290](#) [MBRB30H30CT-1G](#) [BAS 70-02L E6327](#) [DMJ3940-000](#) [SB007-03C-TB-E](#) [SB10015M-TL-E](#) [SB1003M3-TL-E](#) [SK32A-](#)
[TP](#) [SK33B-TP](#) [SK35A-TP](#) [SK38B-LTP](#) [SK38B-TP](#) [NTE505](#) [NTSB30U100CT-1G](#) [VS-6CWQ10FNHM3](#) [CRG04\(T5L,TEMQ\)](#)
[ACDBA1100LR-HF](#) [ACDBA1200-HF](#) [ACDBA140-HF](#) [ACDBA2100-HF](#) [ACDBA240-HF](#) [ACDBA3100-HF](#) [CDBQC0530L-HF](#) [BAT54-](#)
[13-F](#) [ACDBA340-HF](#) [ACDBA260LR-HF](#)